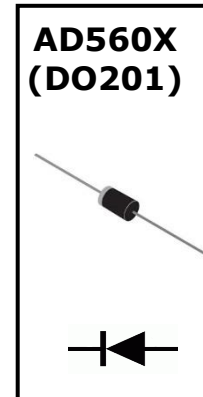


60V 5A ULTRA LOW VF TMOS Schottky

Characteristics Summary

Characteristics	Values	Units
IF(AV)	5	A
VRRM	60	V
VF TYP @ 2A, TJ = 25°C	0.44	V
IR _{MAX} @ TJ = 25°C	25	uA



Features

- Reduced low forward voltage drop (VF) ; better efficiency and cooler operation.
- Reduced high temperature reverse leakage; Increased reliability against thermal runaway failure in high temperature operation.
- Softest, fast switching capability
- 150°C Operating Junction Temperature
- Lead Free Finish, RoHS Compliant

Typical Applications

Device optimized for low forward voltage drop to suitable efficiency in general rectification applications.

- Boost Diode, Blocking Diode, Rectifier, Recirculating Diode

Maximum Ratings Characteristics - (TA = 25°C unless otherwise specified)

Parameter	Symbol	Values	Units
DC Blocking Voltage	V _{RM}	60	V
Working Peak Reverse Voltage	V _{RWM}		V
Peak Repetitive Reverse Voltage	V _{RRM}		V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) – 50% duty cycle	I _D	5	A
Non-Repetitive Peak Forward Surge Current 8.3ms	I _{FSM}	60	A
Typical Thermal Resistance Junction to Ambient (Note 1)	R _{θJA}	30	°C / W
Operating Junction Temperature	T _J	-55 to +150	°C
Storage Junction Temperature	T _{STG}	-55 to +150	

Note 1 : FR-4 PCB, 2 oz Copper. Minimum recommended pad layout

Electrical Characteristics - (TA = 25°C unless otherwise specified)

Parameter	Test Conditions	Symbol	Typ.	Max.	Units	
Forward Voltage	IF = 2 A	VF*	0.44	0.48	V	
	IF = 3 A		0.47	0.51		
	IF = 5 A		0.54	0.59		
	IF = 10 A		0.68	0.73		
	IF = 5 A		TJ = 125°C	0.50		-----
Reverse Current	VR = 60V	IR*	TJ = 25°C	9	25	uA
			TJ = 125°C	4	10	mA

* Short duration pulse test used to minimize self-heating effect.

Characteristics Curves

(TA = 25°C unless otherwise specified)

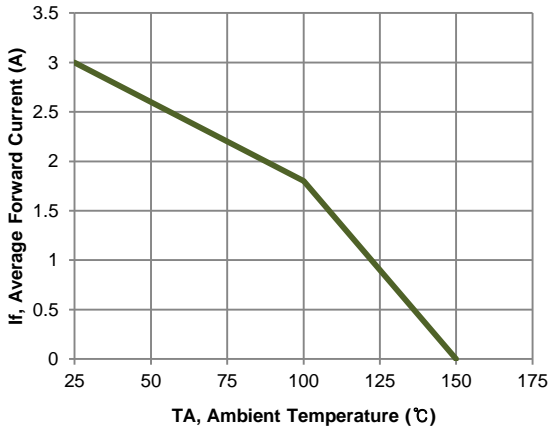


Figure 1 : DC Forward Current Derating

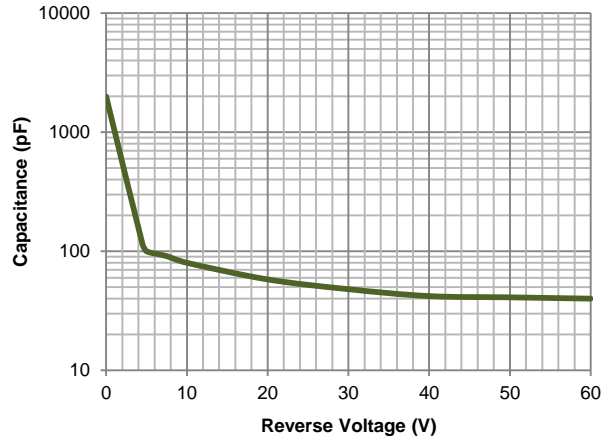


Figure 2 : Typical Junction Capacitance

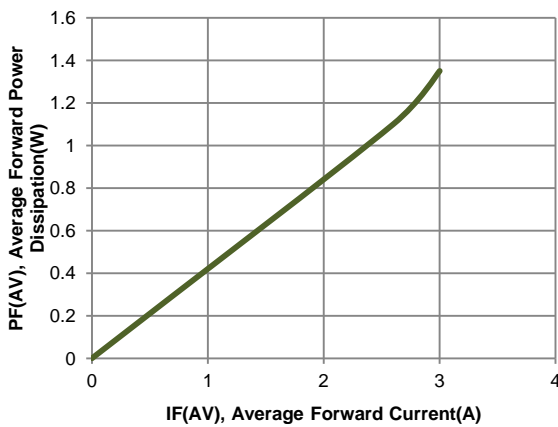


Figure 3. Forward Power Dissipation

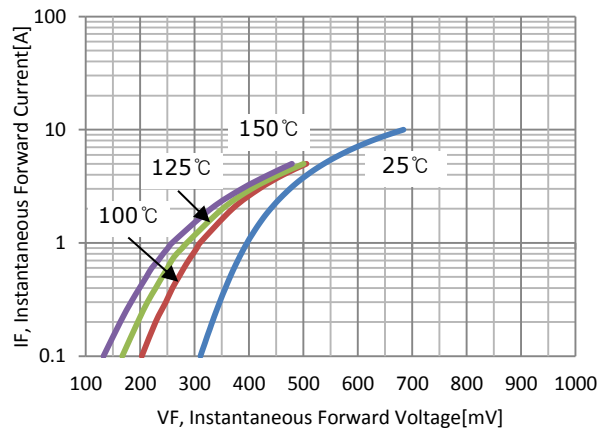


Figure 4. Typical Forward Voltage

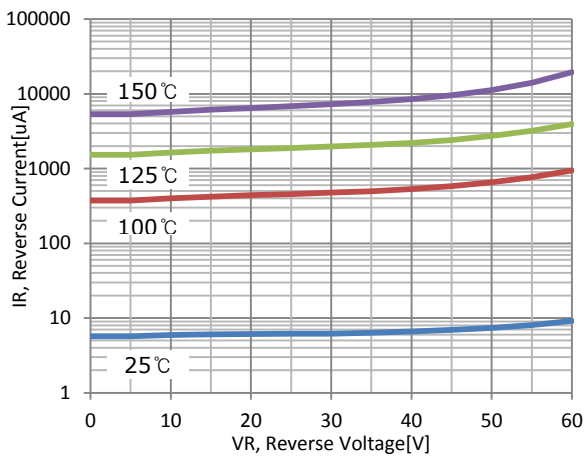
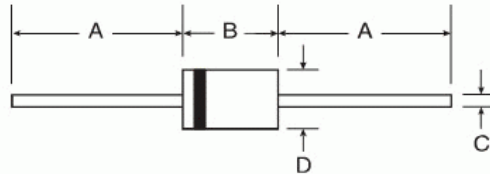


Figure 5. Typical Reverse Current

Ordering Information

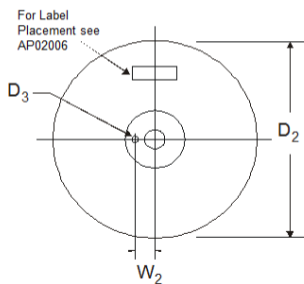
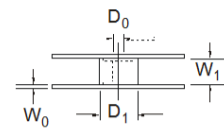
Part No	Package	Packing	Finish	Halogen	Packing Unit
AD560X	DO-201	13" Reel & Tape	Sn	Free	1,200ea

Package Dimension

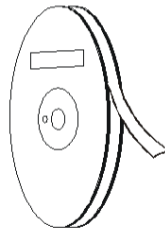


DO-201AD		
Dim	Min	Max
A	25.40	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		

Reel Packing Method



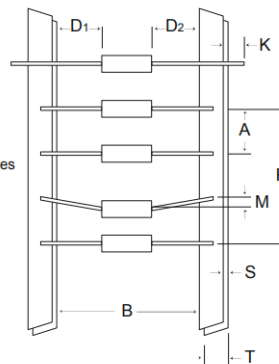
Direction of Unreeling



PRODUCT REEL			
Description	Symbol	Specification(mm)	Alternate(mm)
Arbor Hole Diameter	D ₀	16.6 ± 0.50	30.0 ± 0.50
Core Diameter (O.D)	D ₁	81.0 Typical	81.0 Typical
Reel Diameter	D ₂	345.0 ± 15.0	260.0 ± 15.0
Drive Hole Diameter	D ₃	9.5 ± 0.5	9.5 ± 0.5
Material Thickness	W ₀	2.0 - 4.0	2.0 - 4.0
Reel Width	W ₁	80.0 ± 5.0	65.0 ± 5.0
Drive/ Arbor Hole Spacing	W ₂	27.5 ± 0.5	27.5 ± 0.5

Core material: plastic (blue/black) or metal (neutral)
Reel material: corrugated board or plastic (blue or black)

Dimensions A, M, K, P,
S, & T apply to both sides



REEL AND AMMO PACK TAPING SPECIFICATIONS		
Description	Symbol	Specification (mm)
Component Pitch	A	10.0 ± 0.5
Inside Tape Spacing	B	52.4 ± 1.5
Lead to Lead Eccentricity	D ₁ - D ₂	1.4 max
Lead Extension	K	0.8 max
Lead Bending	M	1.2 max
Cumulative Pitch	P	±1.5 per 6 pitch
Exposed Adhesive	S	0.8 max
Tape Width	T	6.0 ± 0.4
Empty Spaces		< 0.1%
Polarity Marking		All polarized components shall be oriented in the same direction. The cathode tape shall be colored, and the anode tape shall be white or light beige. Anode end must face label-side of reel. See AP02006 for label placement.



Revision History

No	Date	Contents
0	2016-10-25	Initial Brief Datasheet Release

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